## NSN 5962-01-125-7378



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-125-7378 **Body Length:** Between 1.236 inches and 1.290 inches **Body Width:** 0.560 inches **Body Height:** Between 0.130 inches and 0.170 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmed and 3-state output and bipolar

**Inclosure Material:** 

Ceramic

**Inclosure Configuration:** 

Dual-in-line

**Output Logic Form:** 

Transistor-transistor logic

**Input Circuit Pattern:** 

11 input

**Current Rating Per Characteristic:** 

185.00 milliamperes reverse current, dc absolute

**Terminal Surface Treatment:** 

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

**Capitance Rating Per Characteristic:** 

5.00 input picofarads and 8.00 output picofarads

**Time Rating Per Chacteristic:** 

90.00 nanoseconds access

**Memory Device Type:** 

Prom

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

**Demilitarization:** 

Yes - demil/mli

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